Product Summary

$V_{(BR)DSS}$	$R_{DS(on)}$ max	I_D max T_A = +25°C
30V	1.2Ω @ V_{GS} = 4V	415mA
	1.5Ω @ V_{GS} = 2.5V	370mA
	2.2Ω @ V_{GS} = 1.8V	300mA

Description

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.2V Max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

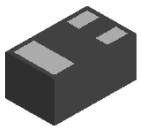
Mechanical Data

- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish – NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.001 grams (Approximate)

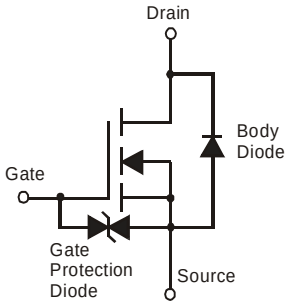


ESD PROTECTED

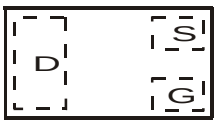
X2-DFN1006-3



Bottom View



Equivalent Circuit



Top View
Pin-Out

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN32D2LFB4-7	DV	7	8	3,000
DMN32D2LFB4-7B	DV	7	8	10,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

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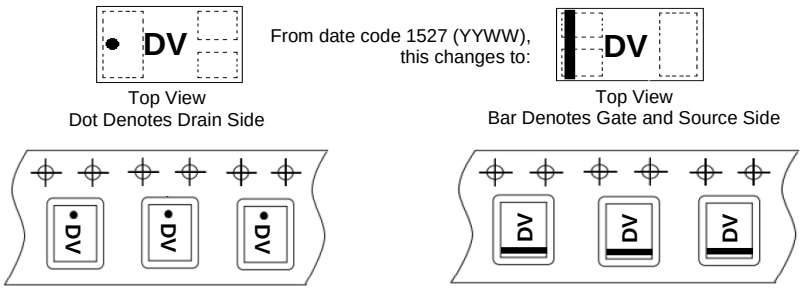
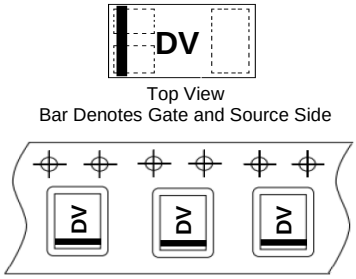
Marking Information

DMN32D2LFB4-7	
DMN32D2LFB4-7B	

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V_{DSS}	30	V
Gate-Source Voltage	V_{GSS}	±10	V
Drain Current (Note 5)	I_D	300	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Total Power Dissipation (Note 5) @T_A = +25°C	P_D	350	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	357	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Note: 5. Device mounted on FR-4 PCB, pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com.

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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage		BV_{DSS}	30	—	—	V	V_{GS} = 0V, I_D = 10μA
Zero Gate Voltage Drain Current	@ T_C = +25°C	I_{DSS}	—	—	1	μA	V_{DS} = 30V, V_{GS} = 0V
Gate-Body Leakage		I_{GSS}	—	—	±10 ±500	μA nA	V_{GS} = ±10V, V_{DS} = 0V V_{GS} = ±5V, V_{DS} = 0V
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage		$V_{GS(th)}$	0.6	—	1.2	V	V_{DS} = V_{GS}, I_D = 250μA
Static Drain-Source On-Resistance		$R_{DS\ (ON)}$	— — —	— — —	2.2 1.5 1.2	Ω	V_{GS} = 1.8V, I_D = 20mA V_{GS} = 2.5V, I_D = 20mA V_{GS} = 4.0V, I_D = 100mA
Forward Transconductance		$\|Y_{fs}\|$	100	—	—	mS	V_{DS} =10V, I_D = 0.1A
Source-Drain Diode Forward Voltage		V_{SD}	0.5	—	1.4	V	V_{GS} = 0V, I_S = 115mA
DYNAMIC CHARACTERISTICS							
Input Capacitance		C_{iss}	—	39	78	pF	V_{DS} = 3V, V_{GS} = 0V f = 1.0MHz
Output Capacitance		C_{oss}	—	10	20	pF	
Reverse Transfer Capacitance		C_{rss}	—	3.6	7.2	pF	
Switching Time	Turn-on Time	t_{on}	—	11	22	nS	V_{DD} = 5V, I_D = 10mA, V_{GS} = 0-5V
	Turn-off Time	t_{off}	—	51	102	nS	

Note: 6. Short duration pulse test used to minimize self-heating effect.

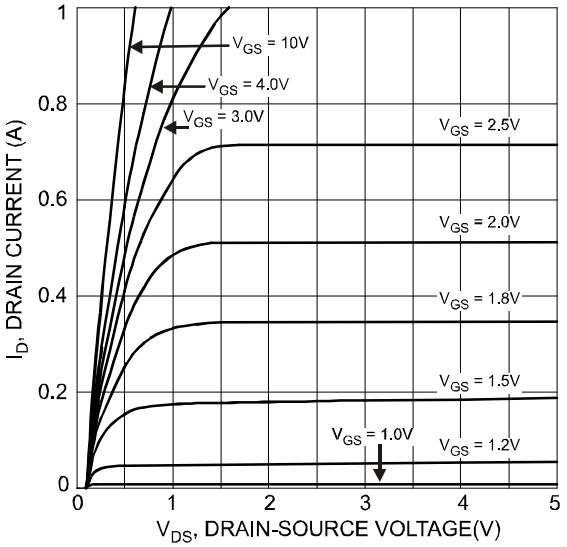

Fig. 1 Typical Output Characteristics

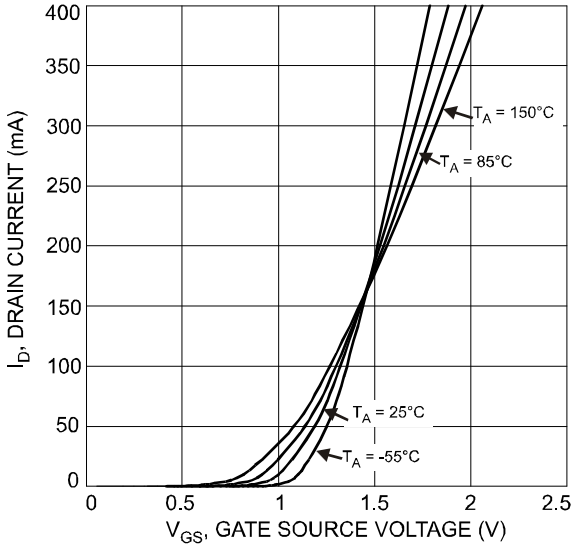

Fig. 2 Typical Transfer Characteristics

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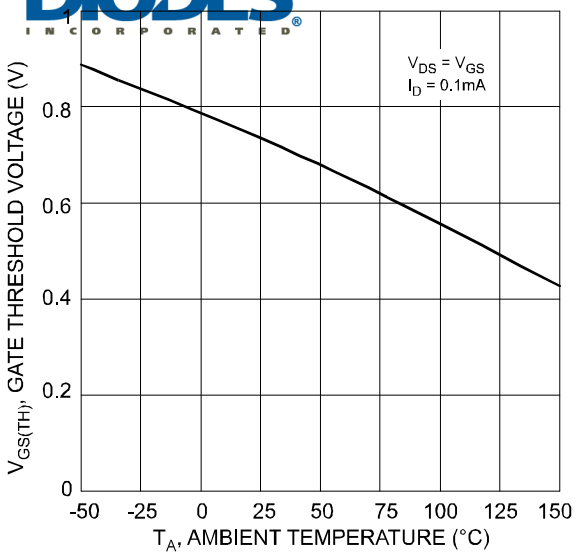

Fig. 3 Gate Threshold Voltage vs. Ambient Temperature

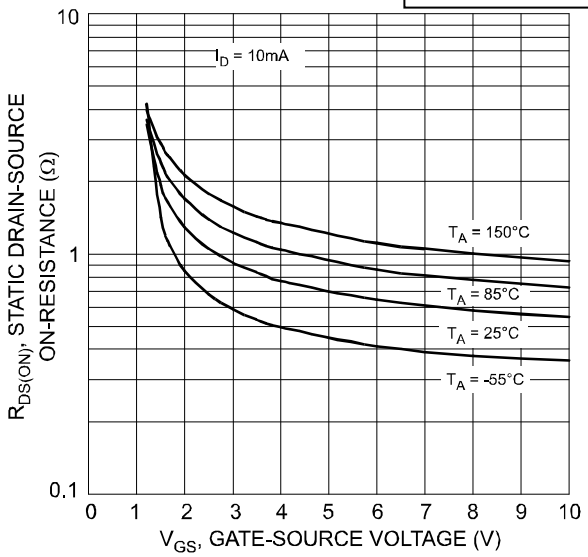

Fig. 4 Static Drain-Source On-Resistance vs. Gate-Source Voltage

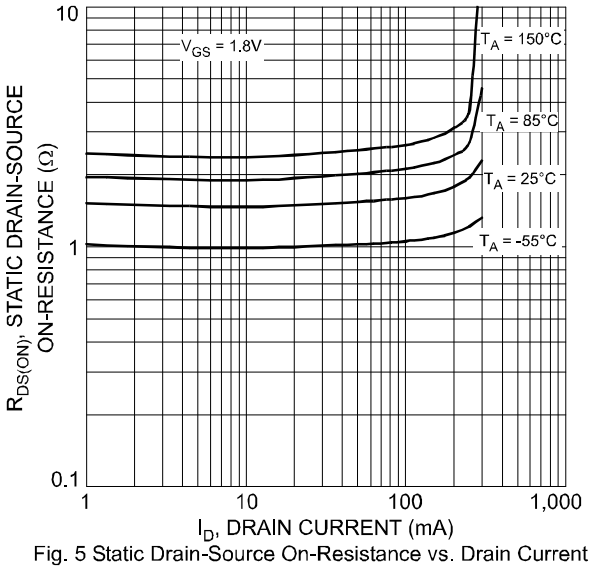

Fig. 5 Static Drain-Source On-Resistance vs. Drain Current

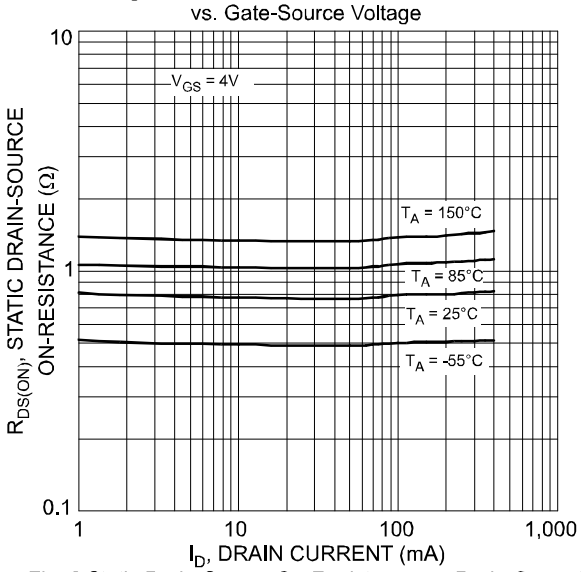

Fig. 6 Static Drain-Source On-Resistance vs. Drain Current

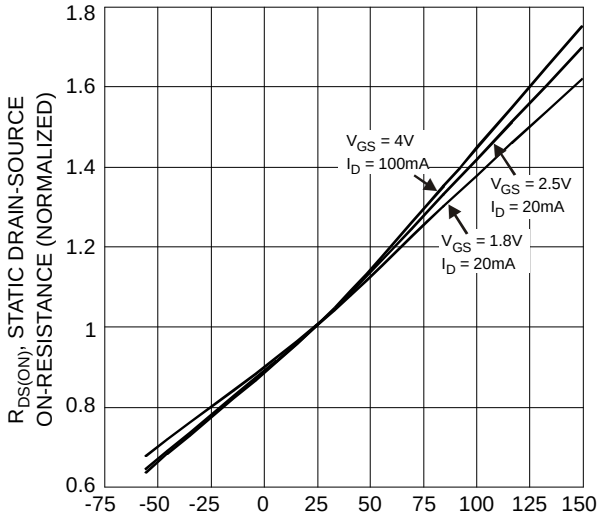

Fig. 7 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

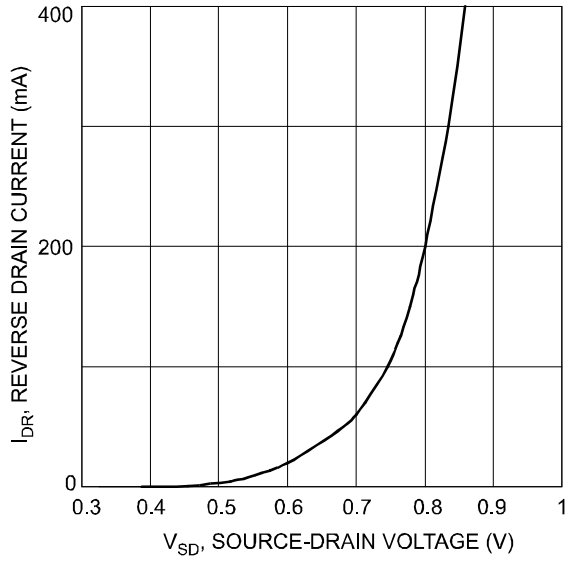

Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

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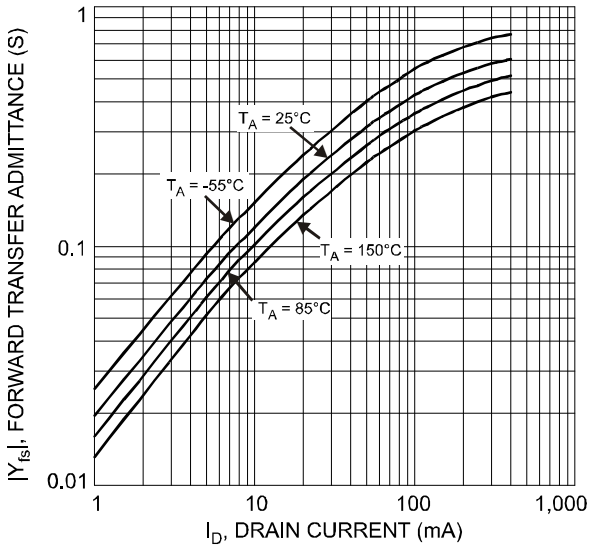


Fig. 9 Forward Transfer Admittance vs. Drain Current

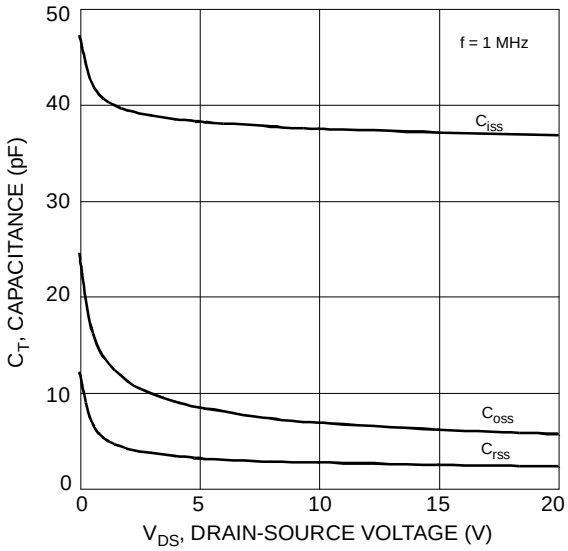
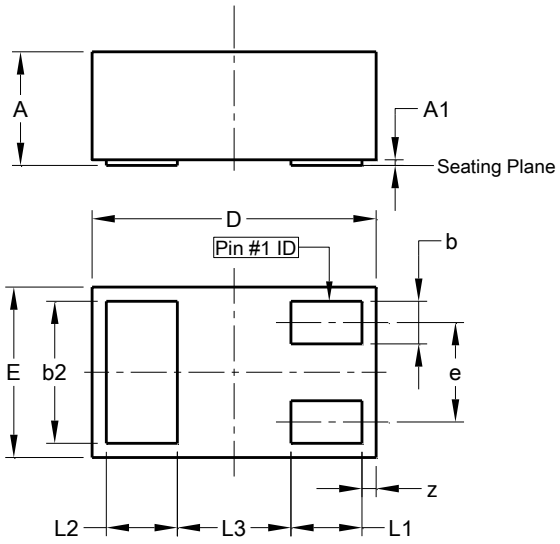


Fig. 10 Typical Capacitance

Package Outline Dimensions

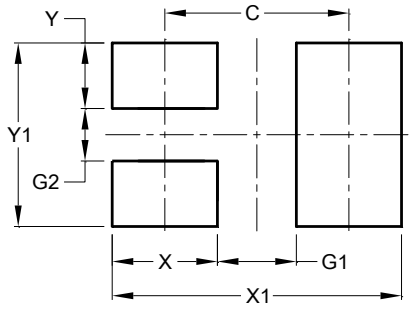
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X2-DFN1006-3			
Dim	**Min**	**Max**	**Typ**
A	-	0.40	-
A1	0.00	0.05	0.03
b	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.05	1.00
E	0.55	0.65	0.60
e	-	-	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
L3	-	-	0.40
z	0.02	0.08	0.05
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	0.70
G1	0.30
G2	0.20
X	0.40
X1	1.10
Y	0.25
Y1	0.70

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